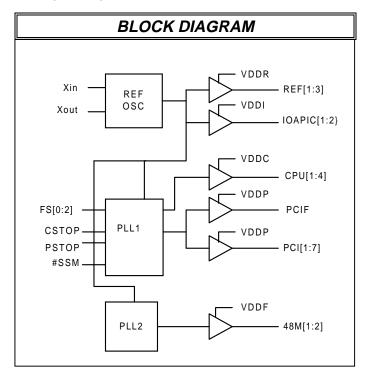


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PRODUCT FEATURES

- Supports Pentium Pentium II & Pro CPUs.
- · Designed to meet Intel chipset specification
- 4 CPU and 8 PCI clocks
- Two 48 MHz fixed clocks for USB and Super IO.
- Separate supply pins for mixed CPU, IOAPIC, and Fixed/PCI clocks
- < 175 ps Max. skew among CPU clocks.
- < 250 ps Max. skew among PCI clocks.
- Controlled current output buffers
- Power management feature
- 2 IOAPIC clocks for multiprocessor support.
- 48-pin SSOP package
- Spread Spectrum EMI reduction mode



	FREQUENCY TABLE										
FS2	S2 FS1 FS0 CPU PCI										
0	0	0	Tri-State	Tri-State							
0	1	1	66 (66.58)*	33.3*							
1	0	0	Ref/2	Ref/4							
1	1	1	100 (99.7)**	33.2**							

NOTE: *Down Spread 1.25% (total)

**Down Spread .5% (total)

CONNECTION DIAGRAM IMISG577D REF1 □VDDR REF3 REF2 VSS 3 VDDI XIN IOAPIC1 XOUT 5 IOAPIC2 VSS 6 VSS PCI_F 7 N/C PCI1 □ VDDC 41 CPU1 VDDP 9 40 PCI2 10 39 CPU2 PCI3 11 VSS 38 VDDC VSS 12 37 PCI4 CPU3 13 36 PCI5 CPU4 VDDP VSS PCI6 16 VDD PCI7 17 32 VSS VSS 31 PSTOP 18 VDD 19 30 CSTOP PD VSS 20 29 #SSM VDDF 21 28 FS0 48M1 22 27 48M2 23 FS1 VSS 24 FS2



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1.557.0100	i Pioduci			PIN	DESCRIPTION
PIN	Pin	PWR	I/O	TYPE	Description
No.	Name		., 0		2 333.1p.1071
4	Xin	VDD	I	OSC1	On-chip reference oscillator input pin. Requires either an external parallel resonant crystal (nominally 14.318 MHz) or externally generated reference signal
5	Xout	VDD	0	OSC1	On-chip reference oscillator output pin. Drives an external parallel resonant crystal when an externally generated reference signal is used, is left unconnected
25, 26, 27	FS(0:2)	-	_	PAD PU	Frequency select input pins. See frequency select table on page 1. These pin has an internal pull-up
40, 39, 36, 35	CPU(1:4)	VDDC	0	BUF1	Clock outputs. CPU frequency table specified on page 1.
45, 44	IOAPIC(1:2)	VDDI	0	BUF2	IOAPIC clock for multi processor support. Fixed frequency at 14.31818 MHz. (2.5 or 3.3 supply = VDDI)
8, 10, 11, 13, 14, 16, 17	PCI(1:7)	VDDP	0	BUF4	PCI bus clocks. See frequency select table on page 1.
7	PCI_F	VDDP	0	BUF4	PCI clock that ceases only when PD (pin 29) is ascerted. See frequency select table on page 1.
3, 6, 12, 18, 20, 24, 32, 34, 38, 43	VSS	-	Р	-	Ground pins for the device.
46	VDDI	-	Р	-	3.3 or 2.5 Volt power supply pins for IOAPIC clock output buffers.
9, 15	VDDP	-	Р	-	3.3 Volt power supply pins for PCI and PCI_F clock output buffers.
21	VDDF	-	Р	-	3.3 Volt power supply pins for 48 MHz clock output buffers.
48	VDDR	-	Р		3.3 Volt power supply pins for reference clock output buffers.
37, 41	VDDC	-	Р	-	3.3 or 2.5 Volt power supply pins for CPU clock output buffers.
19, 33	VDD				Power supply pins for analog circuits and core logic
1, 2, 47	REF(1:3)	VDDR	0	BUF3	Buffered outputs of on-chip reference oscillator.
22, 23	48M(1:2)	VDDF	0	BUF3	Fixed 48 MHz frequency clock outputs.
31	PSTOP	-	I	PAD PU	When driven to a logic low level, this pin will synchronously stop all PCI clocks (except PCI_F) at a logic low level.
30	CSTOP	-	I	PAD PU	When driven to a logic low level, this pin will synchronously stop all CPU clocks at a logic low level.
28	#SSM	-	I	PAD PU	When driven to a logic low level this pin enables EMI reducing Spread Spectrum mode (affects only CPU and PCI clocks).
29	PD	-	I	PAD PU	When this pin is driven to a logic low the IC will enter shutdown mode and ALL internal circuitry is turned off.



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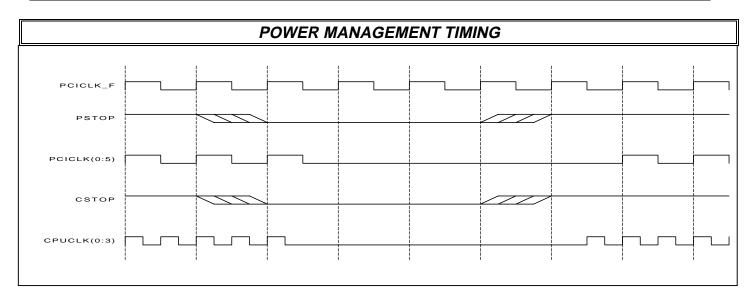
	Outputs									
Descriptions	CPU	PCI, PCIF	48 MHz	REF1:3	IOAPIC					
Tri-State	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z					
Test Mode	TCLK/2	TCLK/4	TCLK/2	TCLK	TCLK					

NOTE: TCLK is a test clock that is driven into the XTAL_IN input during test mode.

POWER MANAGEMENT FUNCTIONS

All PCI (excluding PCI_F) and CPU clocks can be enabled or stopped via the PSTOP and CSTOP input pins. All clocks are stopped in the low state. All clocks maintain a valid high period on transitions from running to stopped and on transitions from stopped to running when the chip was not powered down. On power up, (after bring PD from a low to high state) the VCOs will stabilize to the correct pulse widths within about 0.2 mS. The CPU, and PCI clocks transition between running and stopped by waiting for one positive edge on PCI_F followed by a negative edge on the clock of interest, after which high levels of the output are either enabled or disabled.

CSTOP	PSTOP	PD	CPUCLK	PCICLK	OTHER CLKs	XTAL & VCOs
Х	Х	0	LOW	LOW	LOW	OFF
0	0	1	LOW	LOW	RUNNING	RUNNING
0	1	1	LOW	RUNNING	RUNNING	RUNNING
1	0	1	RUNNING	LOW	RUNNING	RUNNING
1	1	1	RUNNING	RUNNING	RUNNING	RUNNING



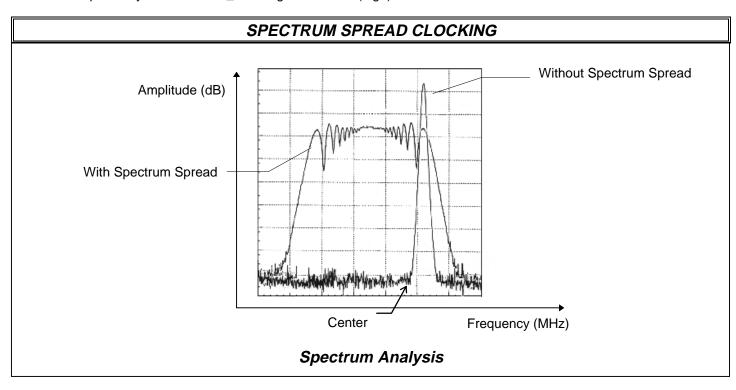


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	Power Management Timing								
		Latency							
Signal	Signal State	No. of rising edges of free running PCICLK (PCIF)							
CSTOP	0 (disabled)	1							
	1 (enabled)	1							
PSTOP	0 (disabled)	1							
	1 (enabled)	1							
PD	1 (normal operation)	3 mS							
	0 (power down)	2 mS _{max}							

NOTES:

- 1? Clock on/off latency is defined in the number of rising edges of free running PCICLKs between the clock disable goes low/high to the first valid clock comes out of the device.
- 2? Power up latency is when PWR_DWN# goes inactive (high) to when the first valid clocks are driven from the device.





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	SPECTRUM SPREADING SELECTION TABLE												
Min Freq (MHz)	Center Freq (MHz)	Max Freq (MHz)	Min Period (nSec)	Average Period* (nSec)	Max Period (nSec)	CPU Frequency	% OF FREQUENCY SPREADING	MODE					
99.25	99.68	100.1	9.99	10.03	10.08	100	.5% (5% + 0%)	Down Spread					
65.59	66.14	66.69	14.99	15.12	15.25	66	1.25% (-1.25% + 0%)	Down Spread					

^{*1} µS sampling period

MAXIMUM RATINGS

Voltage Relative to VSS:

Voltage Relative to VDD:

Storage Temperature:

Operating Temperature:

Maximum Power Supply:

-0.3V

0.3V

0.3V

0°C to +150°C

7V

This device contains circuitry to protect the inputs against damage due to high static voltages or electric field; however, precautions should be taken to avoid application of any voltage higher than the maximum rated voltages to this circuit. For proper operation, Vin and Vout should be constrained to the range:

VSS<(Vin or Vout)<VDD
Unused inputs must always be tied to an appropriate

logic voltage level (either VSS or VDD).

	ELECTRICAL CHARACTERISTICS										
Characteristic	Symbol	Min	Тур	Max	Units	Conditions					
Input Low Voltage	VIL	-	-	0.8	Vdc	-					
Input High Voltage	VIH	2.0	-	-	Vdc	-					
Input Low Current	IIL	-66		-	μA						
Input High Current	IIH			5	μA						
Tri-State leakage Current	loz	-	-	10	μΑ						
Dynamic Supply Current	ldd	-	-	140	mA	CPU = 66.6 MHz, PCI = 33.3 MHz					
Static Supply Current	Isdd	-	-	75	mA	-					
Crystal Oscillator Capacitance	Сх	-	18	-	pF	Xin and Xout crystal load capacitance values (each)					
Short Circuit Current	ISC	25	-	-	mA	1 output at a time - 30 seconds					
VDD = VDDP=	=VDDF =VL	DDR =3.	3V ±5%,	, VDDC, &	VDDI =2.5	V±5%,, TA = 0°C to +70°C					



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	SWITCHING CHARACTERISTICS (See Note 1)										
Characteristic	Symbol	Min	Тур	Max	Units	Conditions					
Output Duty Cycle	-	45	50	55	%	Measured at 1.5V					
CPU to PCI Offset	tOFF	1.5	-	4	ns	CPU load = 20 pF, PCI load = 30 pF measured at 1.5V PCI and 1.25V CPU					
Buffer out Skew All CPU Buffer Outputs	tSKEW ₁	-	-	175	ps	20 pF Load Measured at 1.5V					
Buffer out Skew All PCI Buffer Outputs	tSKEW ₂	-	-	250	ps	30 pF Load Measured at 1.5V					
ΔPeriod Adjacent Cycles	ΔΡ	-	-	<u>+</u> 250	ps	-					
Jitter Spectrum 20 dB Bandwidth from Center	BWJ			500	KHz						
VDD - VDDB	VDDE VDE	ND _2 2	1/ + E 0/ 1	/DDC 9 1	/DDI - 2.51	/_E 9/ TA = 00C to . 700C					

 $VDD = VDDP = VDDF = VDDR = 3.3V \pm 5\%$, VDDC, & $VDDI = 2.5V \pm 5\%$, TA = 0°C to +70°C

TB40A_V BUFFER CHARACTERISTICS FOR CPUCLK(1:4) (See Note 1)									
Characteristic	Symbol	Min	Тур	Max	Units	Conditions			
Pull-Up Current Min	IOH _{min}	22	-	31	mA	Vout = VDD -0.5V			
Pull-Up Current Max	IOH _{max}	37	-	56	mA	Vout = 1.25V			
Pull-Down Current Min	IOL _{min}	30	-	41	mA	Vout = 0.4V			
Pull-Down Current Max	IOL _{max}	75	-	102	mA	Vout = 1.2V			
Dynamic Output Impedance	Z _o	10	-	15	Ohms	66 and 100 MHz			
Rise/Fall Time Max Between 0.4 V and 2.0 V	TRF _{max}	0.5	-	1.6	ns	20 pF Load			
V00 V000	VDDE VDE	20.00		/DDC 6 1	/DD/ 0.51/	150/ TA 000 to 27000			

 $VDD = VDDP = VDDF = VDDR = 3.3V \pm 5\%$, VDDC, & $VDDI = 2.5V \pm 5\%$, $TA = 0^{\circ}C$ to $+70^{\circ}C$



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TB4B BUFFER CHARACTERISTICS FOR IOAPIC (1:2)									
Characteristic Symbol Min Typ Max Units Conditions									
IOH _{min}	22	-	31	mA	Vout = VDDI -0.5V				
IOH _{max}	37	-	56	mA	Vout = 1.25V				
IOL _{min}	30	-	41	mA	Vout = 0.4V				
IOL _{max}	75	-	102	mA	Vout = 1.2V				
TRF	0.5	-	1.6	nS	20 pF Load				
•	Symbol IOH _{min} IOH _{max} IOL _{min} IOL _{max}	Symbol Min IOH _{min} 22 IOH _{max} 37 IOL _{min} 30 IOL _{max} 75	Symbol Min Typ IOH _{min} 22 - IOH _{max} 37 - IOL _{min} 30 - IOL _{max} 75 -	Symbol Min Typ Max IOH _{min} 22 - 31 IOH _{max} 37 - 56 IOL _{min} 30 - 41 IOL _{max} 75 - 102	Symbol Min Typ Max Units IOH _{min} 22 - 31 mA IOH _{max} 37 - 56 mA IOL _{min} 30 - 41 mA IOL _{max} 75 - 102 mA				

 $VDD = VDDP = VDDF = VDDR = 3.3V \pm 5\%$, VDDC, & $VDDI = 2.5V \pm 5\%$, $TA = 0^{\circ}C$ to $+70^{\circ}C$

TB4 BUFFER CHARACTERISTICS FOR REF(1:3)								
Characteristic	Symbol	Min	Тур	Max	Units	Conditions		
Pull-Up Current Min	IOH _{min}	18	-	23	mA	Vout = VDD -0.5V		
Pull-Up Current Max	IOH _{max}	44	-	64	mA	Vout = 1.25V		
Pull-Down Current Min	IOL _{min}	18	-	25	mA	Vout = 0.4V		
Pull-Down Current Max	IOL _{max}	50	-	70	mA	Vout = 1.2V		
Dynamic Output Impedance	Z _o	18	-	25	Ohms	66 and 100 MHz		
Rise/Fall Time Between 0.4 V and 2.4 V	TRF	0.5	-	2.0	ns	20 pF Load		

 $VDD = VDDP = VDDF = VDDR = 3.3V \pm 5\%$, VDDC, & $VDDI = 2.5V \pm 5\%$, TA = 0°C to +70°C

TB5 BUFFER CHARACTERISTICS FOR 48(1:2) MHz									
Symbol	Min	Тур	Max	Units	Conditions				
IOH _{min}	13	-	17	mA	Vout = VDD - 0.5V				
IOH _{max}	30	-	44	mA	Vout = 1.5V				
IOL _{min}	13	-	19	mA	Vout = 0.4V				
IOL _{max}	32	-	44	mA	Vout = 1.5V				
Z _o	18	-	25	Ohms	66 and 100 MHz				
TRF	0.5	-	2.0	ns	20 pF Load				
	Symbol IOH _{min} IOH _{max} IOL _{min} IOL _{max}	Symbol Min IOH _{min} 13 IOH _{max} 30 IOL _{min} 13 IOL _{max} 32 Z _o 18	Symbol Min Typ IOH _{min} 13 - IOH _{max} 30 - IOL _{min} 13 - IOL _{max} 32 - Z _o 18 -	Symbol Min Typ Max IOH _{min} 13 - 17 IOH _{max} 30 - 44 IOL _{min} 13 - 19 IOL _{max} 32 - 44 Z _o 18 - 25	Symbol Min Typ Max Units IOH _{min} 13 - 17 mA IOH _{max} 30 - 44 mA IOL _{min} 13 - 19 mA IOL _{max} 32 - 44 mA Z _o 18 - 25 Ohms				

 $VDD = VDDP = VDDF = VDDR = 3.3V \pm 5\%$, VDDC, & $VDDI = 2.5V \pm 5\%$,, $TA = 0^{\circ}C$ to $+70^{\circ}C$

Note 1: Switching Characteristics are compliant with Intel timing specification when spread spectrum EMI reducing modulation is enabled and/or disabled.



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TB4 BUFFER CHARACTERISTICS FOR PCICLK(1:8,F)(See Note 1)							
Characteristic	Symbol	Min	Тур	Max	Units	Conditions	
Pull-Up Current Min	IOH _{min}	18	-	23	mA	Vout = VDD05V	
Pull-Up Current Max	IOH _{max}	44	-	64	mA	Vout = 1.5V	
Pull-Down Current Min	IOL _{min}	18	-	25	mA	Vout = 0.4V	
Pull-Down Current Max	IOL _{max}	50	-	70	mA	Vout = 1.5V	
Rise/Fall Time Between 0.4 V and 2.4 V	TRF	0.5	-	2.0	ns	30 pF Load	

 $VDD = VDDP = VDDF = VDDR = 3.3V \pm 5\%$, VDDC, & $VDDI = 2.5V \pm 5\%$, $TA = 0^{\circ}C$ to $+70^{\circ}C$

CRYSTAL AND REFERENCE OSCILLATOR PARAMETERS						
Characteristic	Symbol	Min	Тур	Max	Units	Conditions
Frequency	Fo	12.00	14.31818	16.00	MHz	
Tolerence	TC	-	-	+/-100	PPM	Calibration note 2
	TS	-	ı	+/- 100	PPM	Stability (Ta -10 to +60C) note 2
	TA	-	-	5	PPM	Aging (first year @ 25C) note 2
Mode	ОМ	-	-	-		Parallell Resonant
Pin Capacitance	СР		32		pF	Capacitance of XIN and Xout pins
DC Bias Voltage	V_{BIAS}	0.3Vdd	Vdd/2	0.7Vdd	V	
Startup time	Ts	-	-	30	μS	
Load Capacitance	CL	-	20	-	pF	note 2
Effective Series resonant resistance	R1	-	-	40	Ohms	
Power Dissipation	DL	-	-	0.10	mW	note 2
Shunt Capacitance	СО	-		7	pF	
X1 and X2 Load	CL		17		pF	internal crystal loading gapacitors on each pin (to ground)

For maximum accuracy, the total circuit loading capacitance should be equal to CL. This loading capacitance is the effective capacitance across the crystal pins and includes the device pin capacitance (CP) in parallel with any circuit traces, the clock generator and any onboard discrete load capacitors.

Budgeting Calculations

Typical trace capacitance, (< half inch) is 4 pF, Load to the crystal is therefore

4.0 pF

Clock generator internal pin capacitance of 16 pF, Load to the crystal is therefore

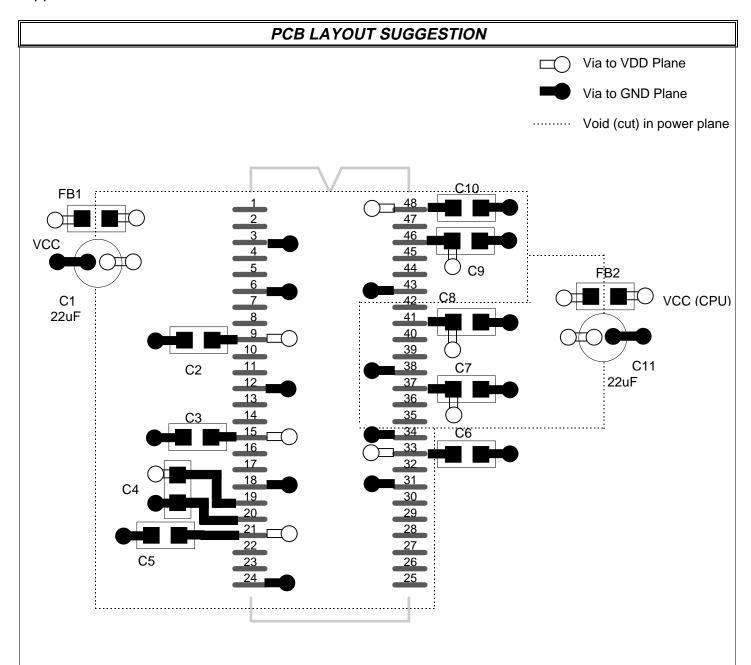
16.0 pF

the total parasitic capacitance would therefore be = 20.0 pF.(matching CL)

Note 2: It is recommended but not mandatory that a crystal meets these specifications.



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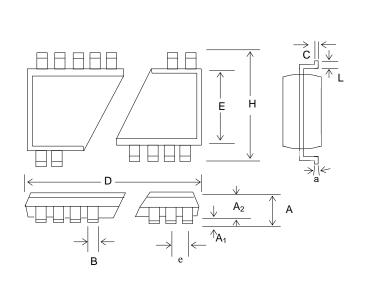


This is only a layout recommendation for best performance and lower EMI. The designer may choose a different approach but C2, C3, C4, C5, C6, C7, C8, C9, and C10 (all are 0.1 uf) should always be used and placed as close to their VDD pins as is physically possible. The topological hookup of C4 with respect to its power and ground vias is especially important.



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PACKAGE DRAWING AND DIMENSIONS



48 PIN SSOP OUTLINE DIMENSIONS						
		INCHES		MILLIMETERS		
SYMBOL	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.095	0.102	0.110	2.41	2.59	2.79
A ₁	0.008	0.012	0.016	0.20	0.31	0.41
A2	0.085	0.090	0.095	2.16	2.29	2.41
b	0.008	0.010	0.0135	0.203	0.254	0.343
С	0.005	.008	0.010	0.127	0.20	0.254
D	0.620	0.625	0.637	15.75	15.88	16.18
Е	0.291	0.295	0.299	7.39	7.49	7.59
е	C	0.0256 BS	С	0.640 BSC		
Н	0.395	0.408	0.420	10.03	10.36	10.67
L	0.024	0.030	0.040	0.61	0.76	1.02
а	00	40	8º	00	4º	80

ORDERING INFORMATION					
Part Number	Package Type	Production Flow			
IMISG577DYB	48 PIN SSOP	Commercial, 0°C to +70°C			

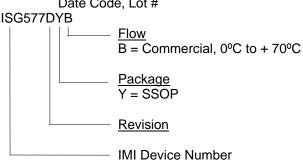
The ordering part number is formed by a combination of device number, device revision, package style, and Note: screening as shown below.

Marking: Example: IMI

SG577DYB

Date Code, Lot #

IMISG577DYB



https://findchips.com/search/sg577d